Chapter 4

Spin Valves

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Review of Last Class

1. Magnetoresistance and ordinary MR

2. Anisotropic MR

3. Tunneling AMR

4. Colossal MR

5. Giant MR

6. Tunneling MR

7. Spin Hall MR

8. Nonlocal MR

9. Hanle MR

Outline 1 and 1 an

1. Spin valves and spin injection

2. Spin valves based on Metal and Superconductor

3. Spin valves based on Semiconductor and Quantum materials

This Class

1. Spin valves and spin injection

Outline

1. Vertical Spin valves

2. From Vertical to Lateral Spin valves

3. Spin injection

Outline |

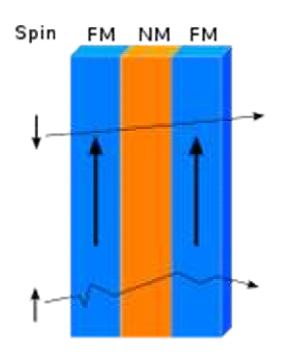
1. Vertical Spin valves

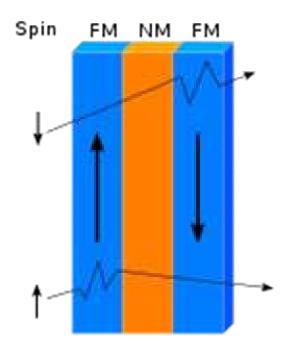
Valve



Valves



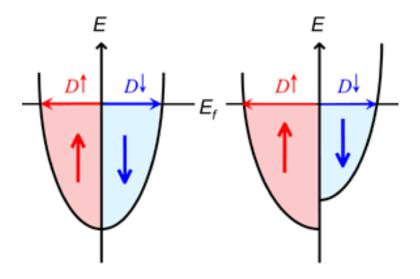




Low Resistance State

High Resistance State

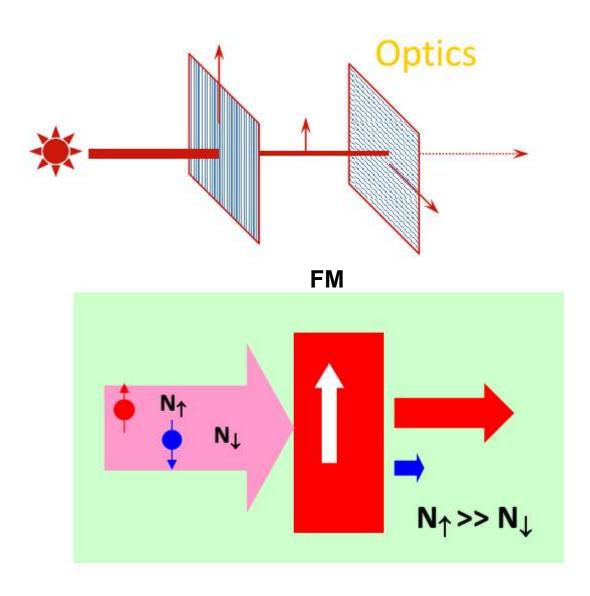
Ferromangetic



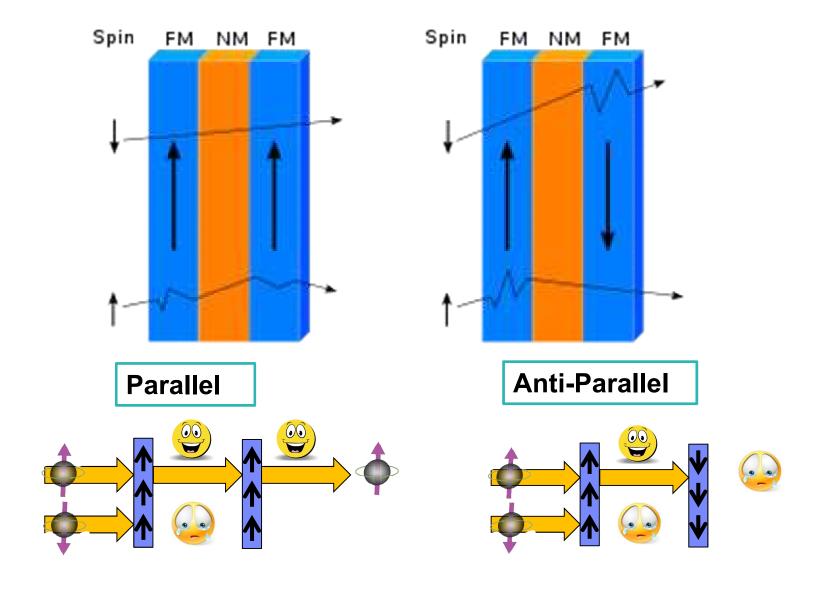
$$P = \frac{D_{\uparrow} - D_{\downarrow}}{D_{\uparrow} + D_{\downarrow}}$$

Nonmagnetic

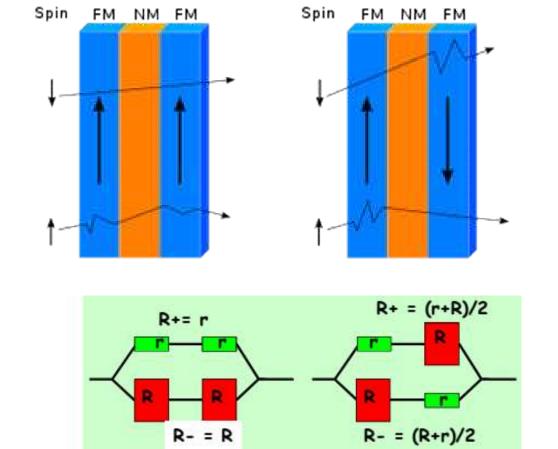
Julie Model



Julie Model



Julie Model



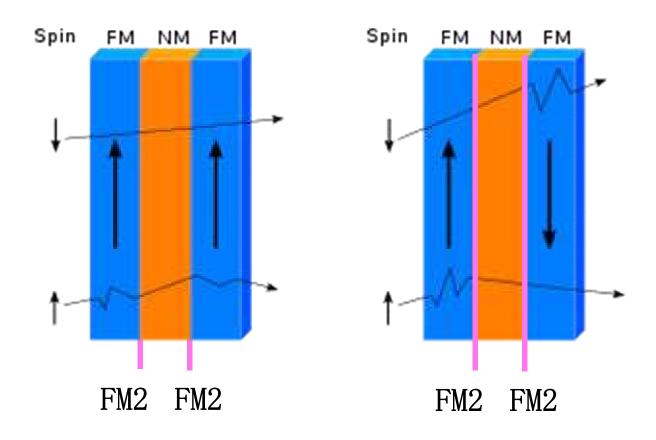
$$R_P = \frac{Rr}{R+r} \approx r < R_{AP} = \frac{R+r}{4}$$

Two examples:

1) Insertion of thin FM layer

2) MgO tunnel barrier

1) Insertion of thin FM layer



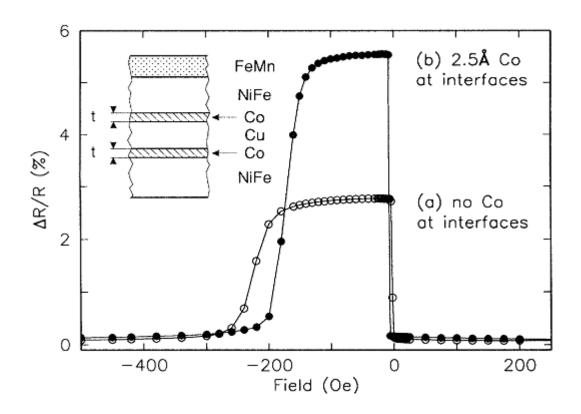
Question: What happens?

1) Insertion of thin FM layer

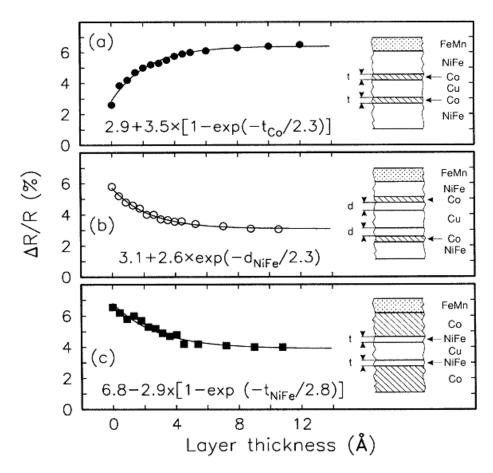
Julie model: two spin current model, then the interface should not matter. The MR depends on the spin polarization of the FMs.

However, this is not the experimental observation.

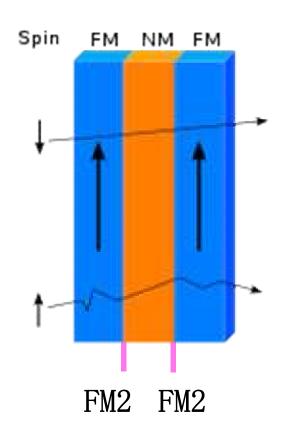
1) Insertion of thin FM layer



1) Insertion of thin FM layer



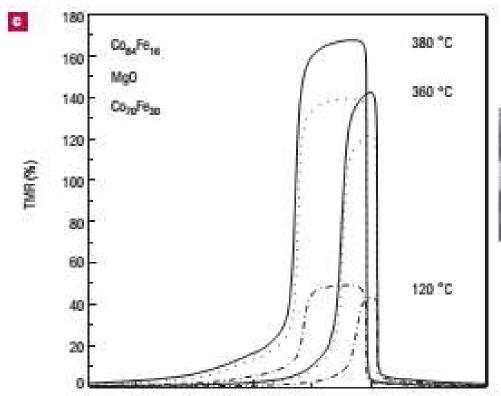
1) Insertion of thin FM layer



Origin of Enhanced MR of Magnetic Multilayers:

Spin-Dependent
Scattering from Magnetic
Interface States

2) MgO tunnel barrier

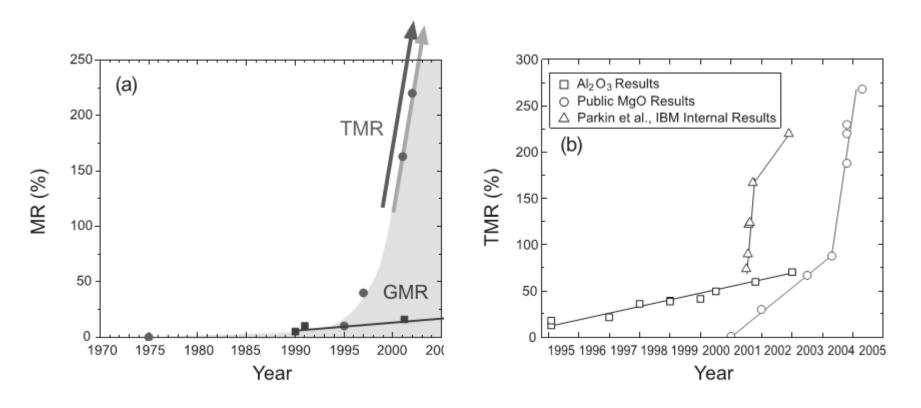


Epitaxial MgO



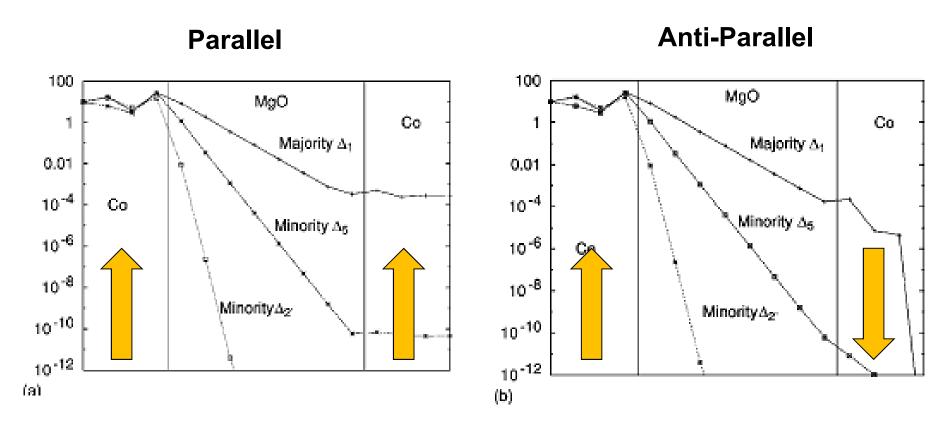
Parkin, et al, Nature Mater (2004) Yuasa, et al, Nature Mater (2004)

2) MgO tunnel barrier



Maekawa, Book Concepts in Spin electronics (2006)

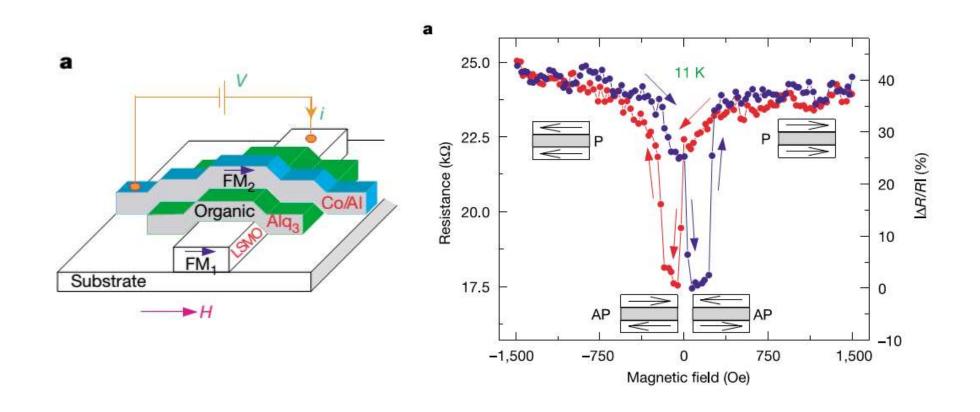
MgO barrier for tunneling: MR >100%



 Δ_1 , symmetry, slow decaying Tunneling of Co majority spin (SP)

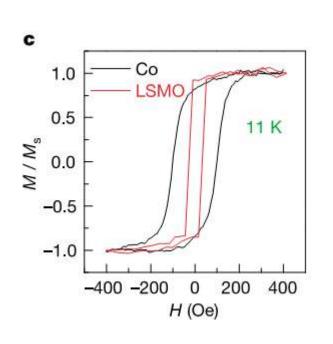
Zhang & Butler, et al, PRB (2004)

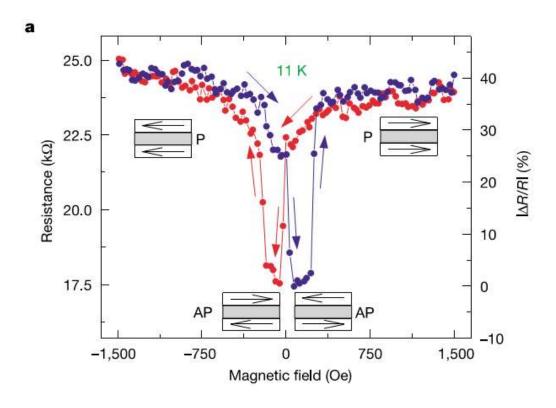
Organic Materials



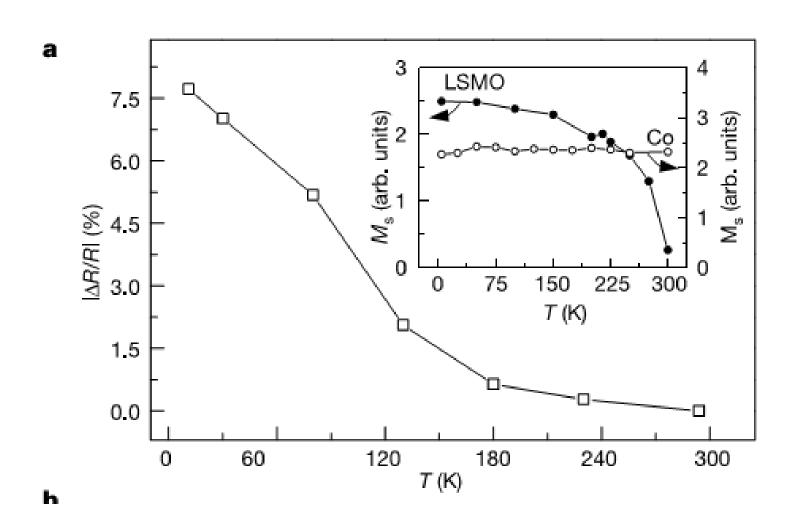
Xiong, et al, Nature (2004)

Organic Materials

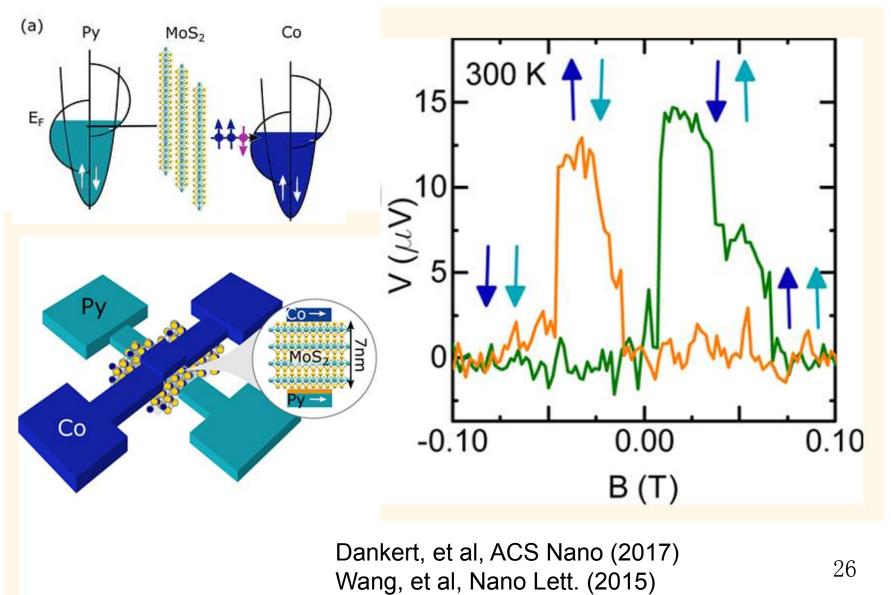




Organic Materials



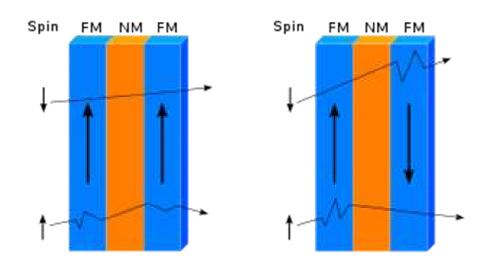
2D Materials

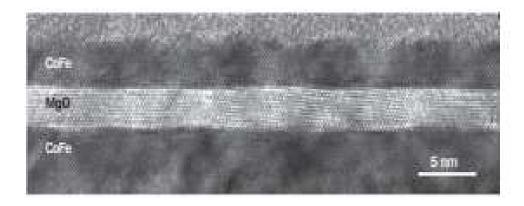


Outline

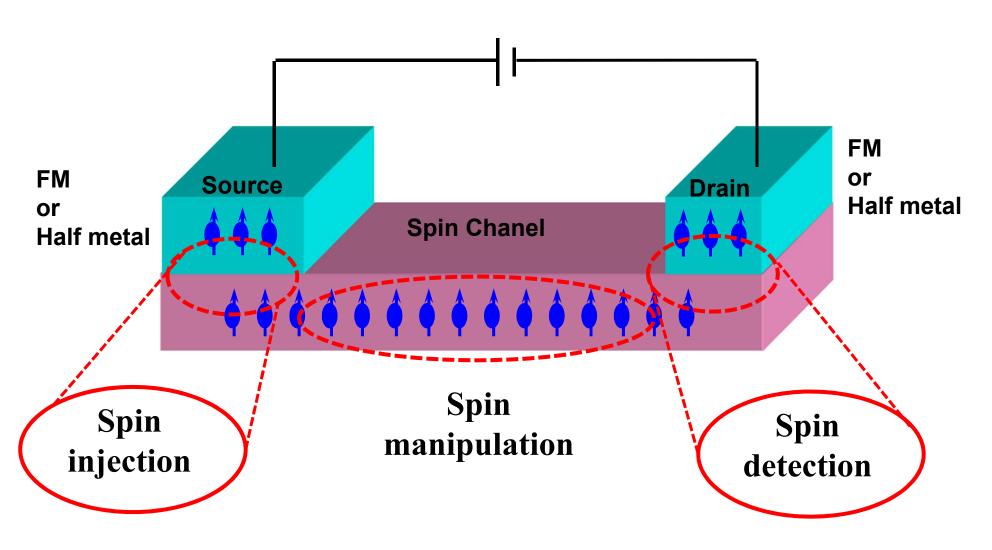
2. Why Lateral Spin Valves

Lateral Spin valves





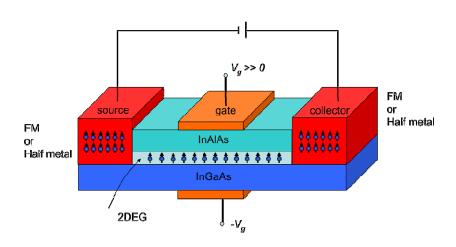
Lateral Spin valves

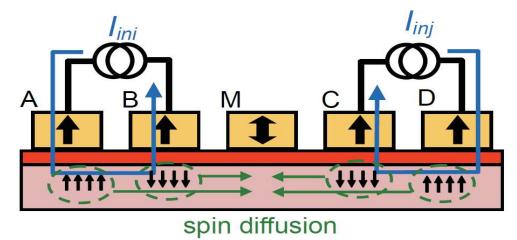


Lateral Spin valves

Spin transistor

Spin logic and computing

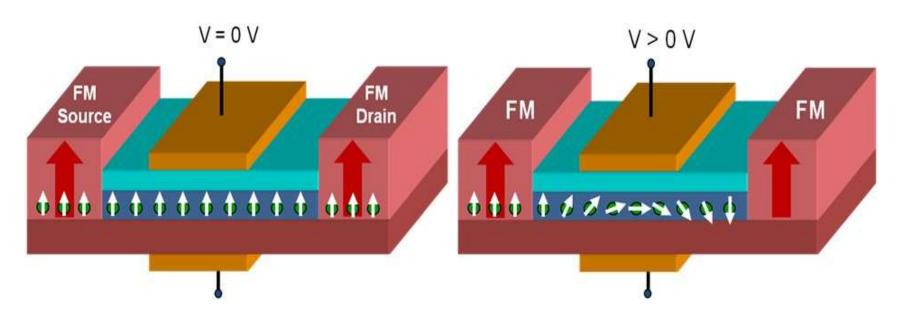




Datta & Das, APL (1990)

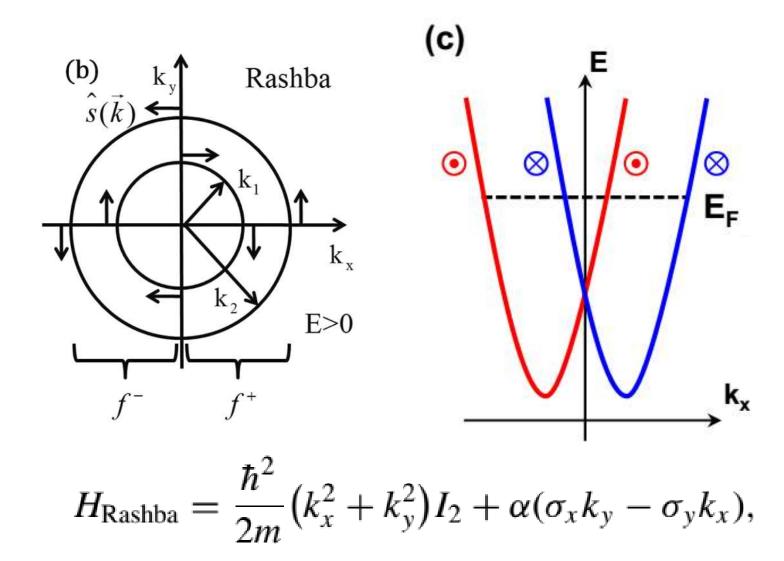
Dery, et al, Nature (2007) Behin-Aein, et al, Nat. Nano (2010). Dery, et al, IEEE Trans. Elec. Dev. (2012)

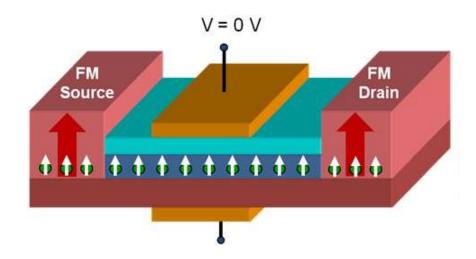
Spin transistor



Electronic analog of the electro - optic modulator - Scitation scitation.aip.org/content/aip/journal/apl/56/7/10.../1.102730 ▼ 翻译此页作者: S Datta - 1990 - 被引用次数: 4147 - 相关文章 1990年2月12日 - 10.1063/1.102730. Supriyo Datta¹ and Biswajit Das¹ ... Abstract; Full Text; References (12); Cited By (2579); Data & Media; Metrics; Related ...

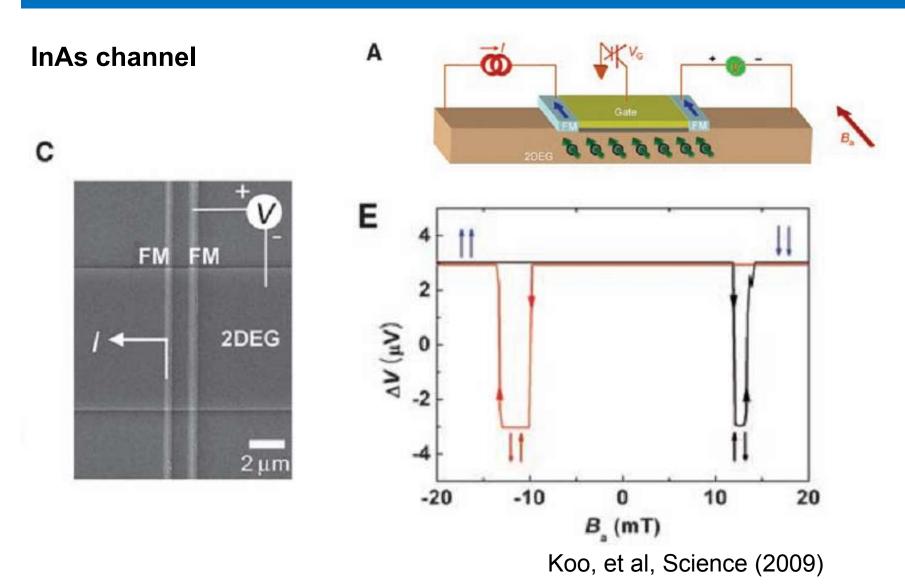
Rashba field

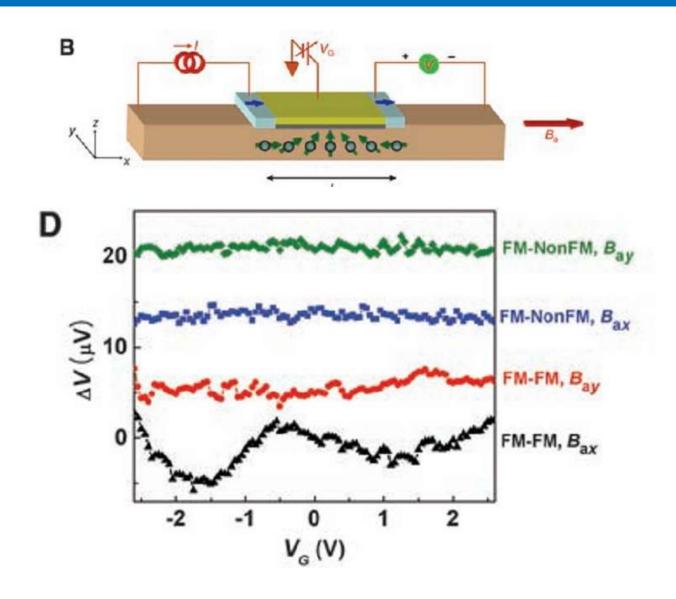


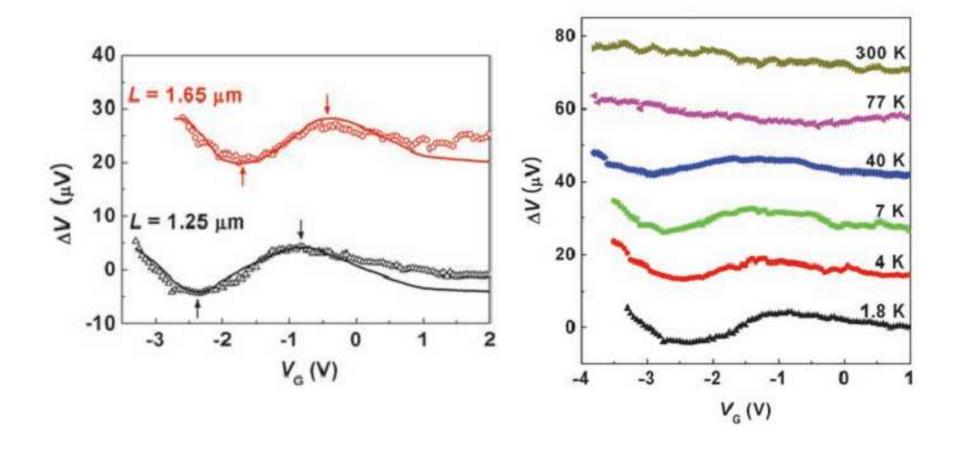


- 1) Long spin diffusion length
- 2) Large Rashba parameter → Rashba field

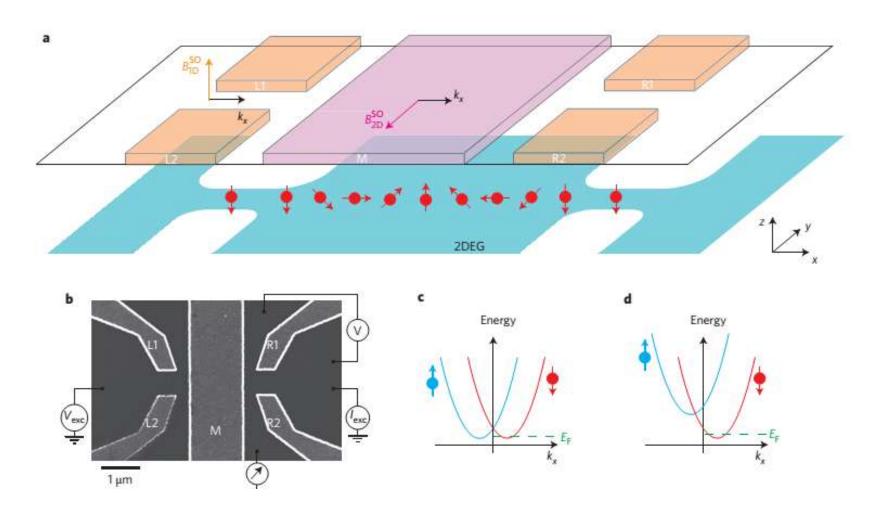
Datta & Das, APL (1990)





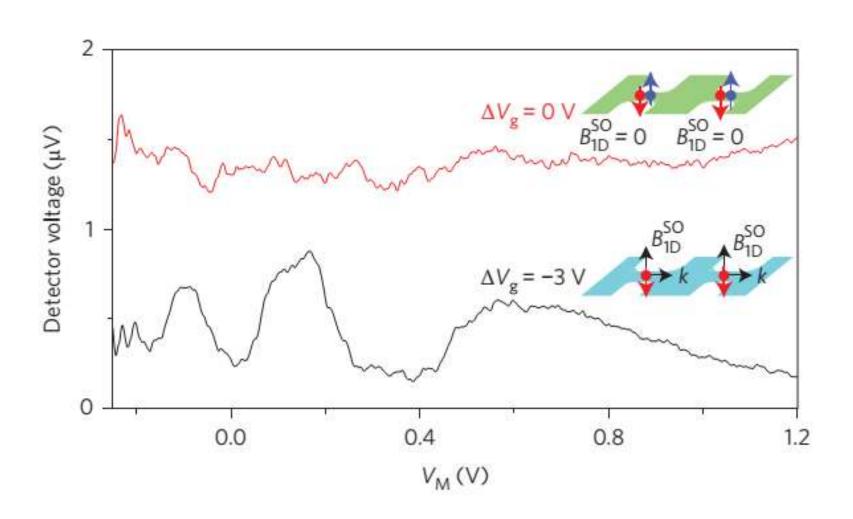


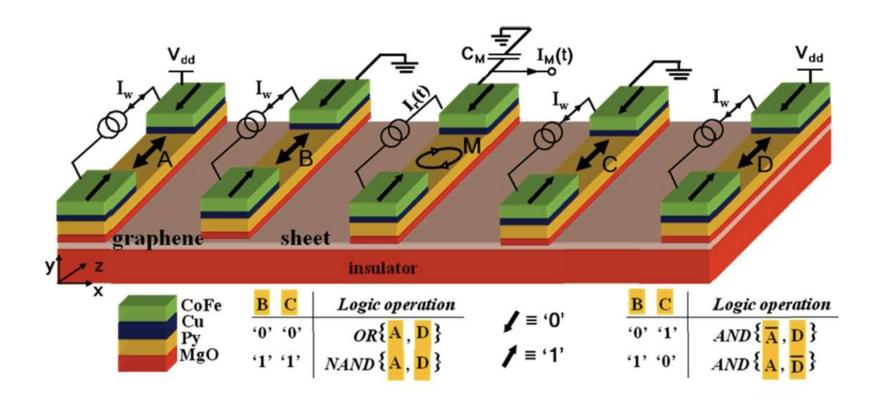
Spin FET



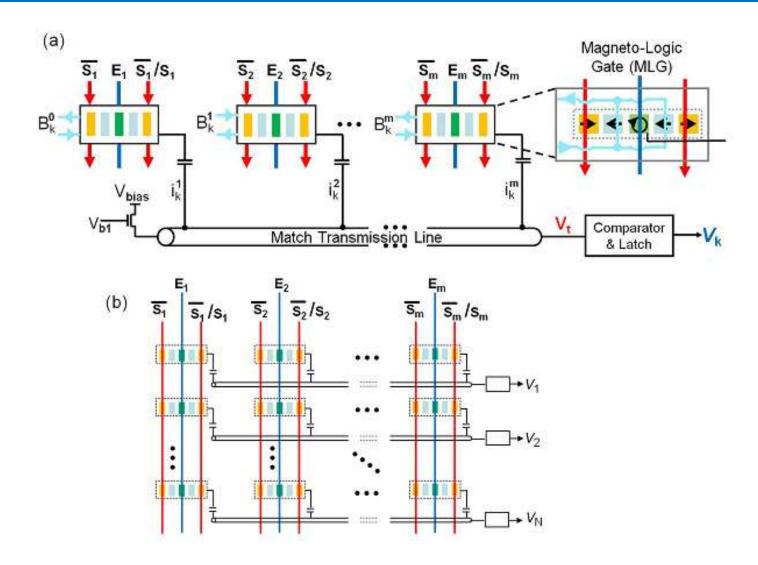
Chuang, et al, Nature Nanotech (2014)

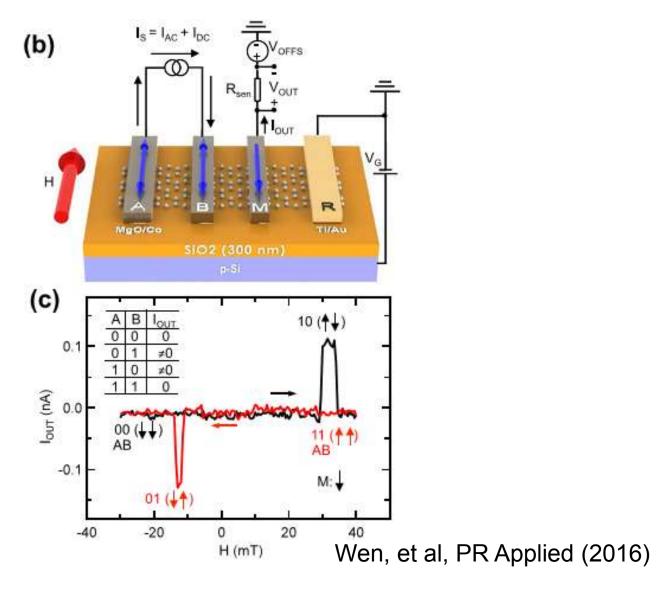
Spin FET

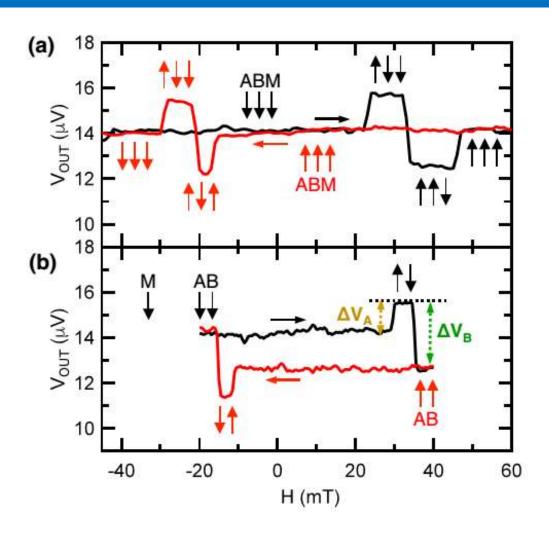


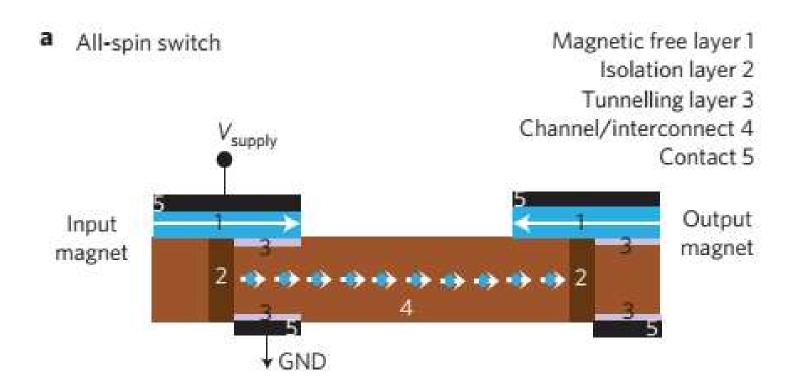


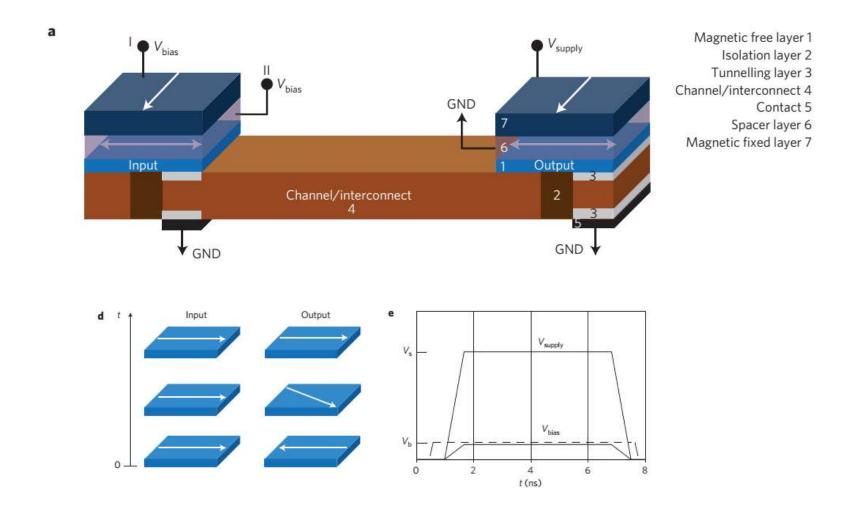
Dery, et al, Nature (2007) Dery, et al, IEEE Trans. Elec. Dev. (2012)



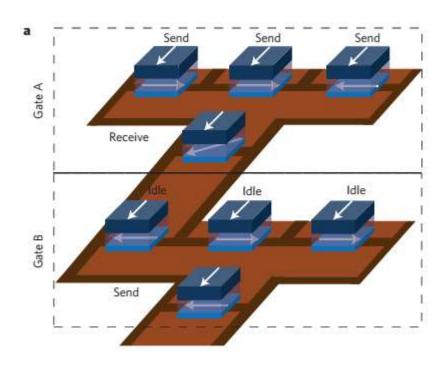


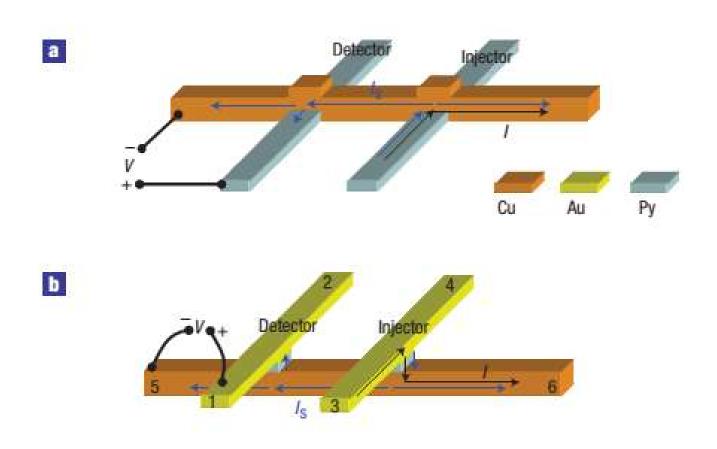




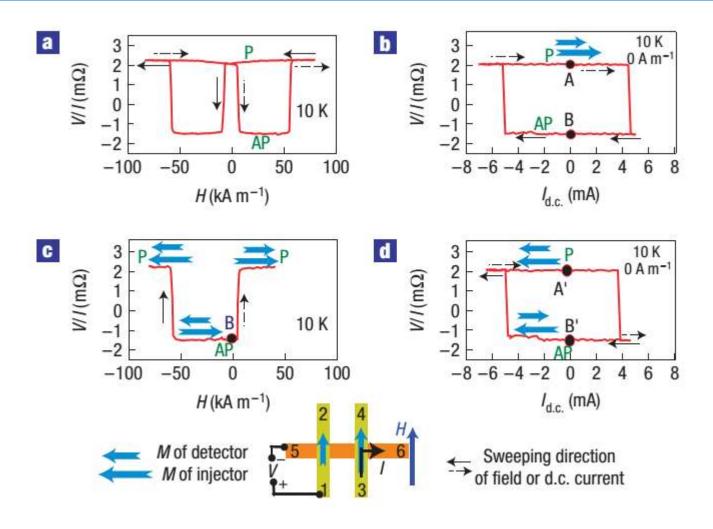


Behin-Aein, et al. Nature Nanotech. (2010)

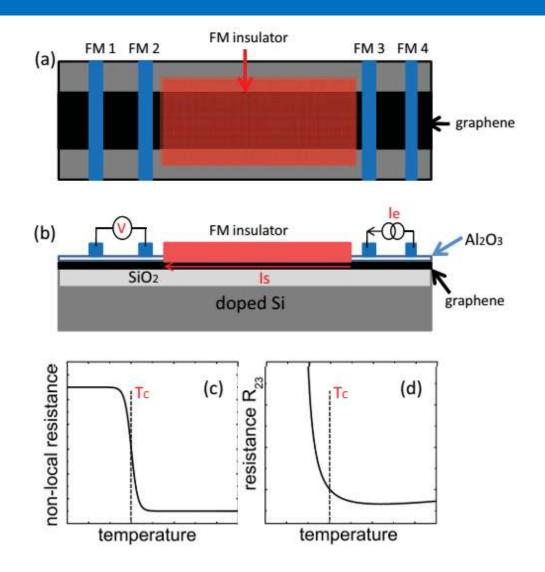




Yang, et al. Nature Nanotech. (2008)



Spin Superconductor

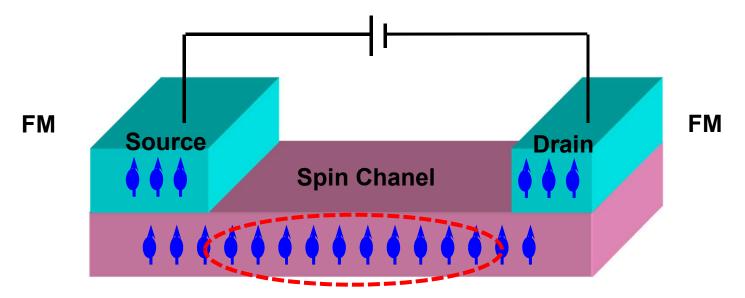


ICQM: Sun & Xie, PRB (2011), Nature Comm (2013)

Summary

Vertical Spin valves

Lateral Spin valves



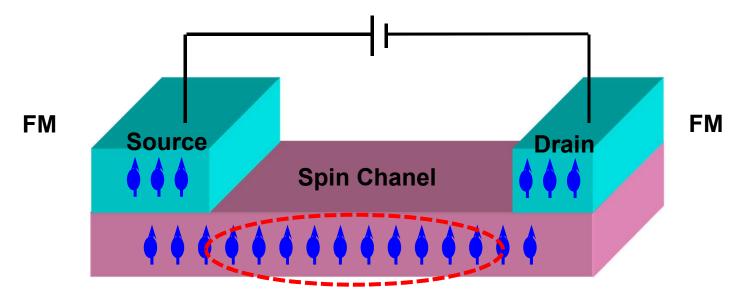
Spin manipulation

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Summary

Vertical Spin valves

Lateral Spin valves



Spin manipulation

Outline 1 and 1 and 1

3. Spin injection

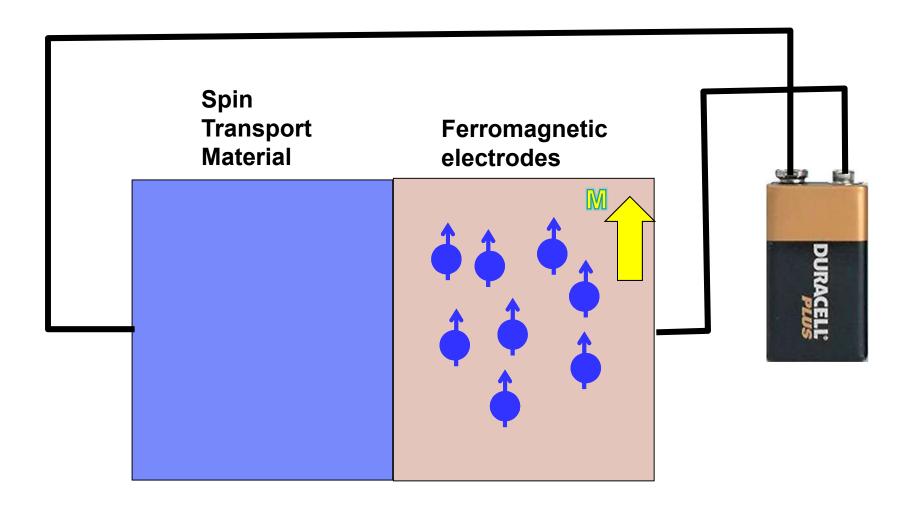
☐ Electrical

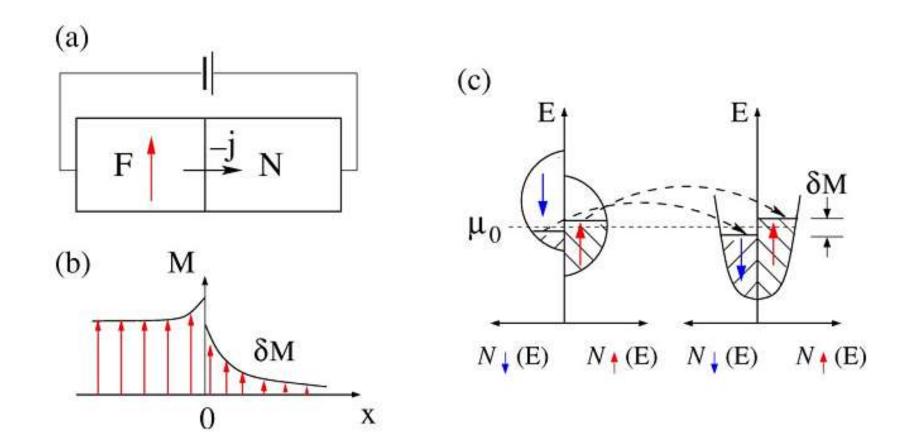
☐ Optical

□ Dynamic

3. Spin injection

☐ Electrical





Zutic, et al, Rev. Mod. Phys. (2004)

Charge current:

Einstein relation

$$j = \sigma \nabla \mu$$

$$\sigma = q^2 ND$$

Spin current:

$$egin{aligned} egin{aligned} egin{aligned\\ egin{aligned} egi$$

Spin dependent chemical potential:

$$\mu_{\uparrow} = (\frac{qD}{\sigma_{\uparrow}})\delta n_{\uparrow} - \emptyset$$

$$\mu = (\frac{qD}{\sigma})\delta n - \emptyset$$

$$\delta n_{\uparrow} = n_{\uparrow} - n_{\uparrow 0}$$

D: diffusion coefficient

σ: conductivity

Ø: electrical potential

Continuity:

$$egin{aligned}
abla j _{\uparrow} &= +q[rac{\delta n}{ au}_{\uparrow\downarrow} - rac{\delta n}{ au}_{\downarrow\uparrow}] \
abla j _{\downarrow} &= -q[rac{\delta n}{ au}_{\downarrow\uparrow} - rac{\delta n}{ au}_{\downarrow\uparrow}] \end{aligned}$$

Charge vs. Spin

$$\sigma = \sigma_{\uparrow} + \sigma_{\downarrow}$$
 $N = N_{\uparrow} + N_{\downarrow}$

At the balance:

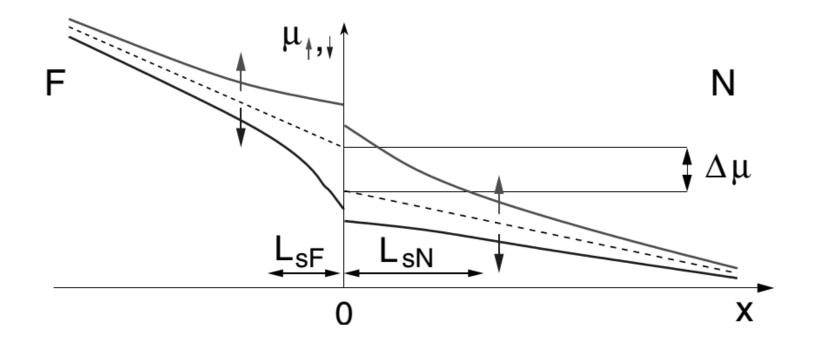
$$\frac{N}{\tau} - \frac{N}{\tau} = 0$$

Interfacial Spin accumulation

$$\mu_{\mathcal{S}} = \mu_{\uparrow} - \mu_{\downarrow}$$

$$\delta S = \delta n_{\uparrow} - \delta n_{\downarrow}$$

$$\mu_{S} = \frac{1}{2q} \frac{N_{\uparrow} + N_{\downarrow}}{N_{\uparrow} N_{\downarrow}} (\delta n_{\uparrow} - \delta n_{\downarrow})$$



Zutic, et al, Rev. Mod. Phys. (2004)

Spin diffusion length

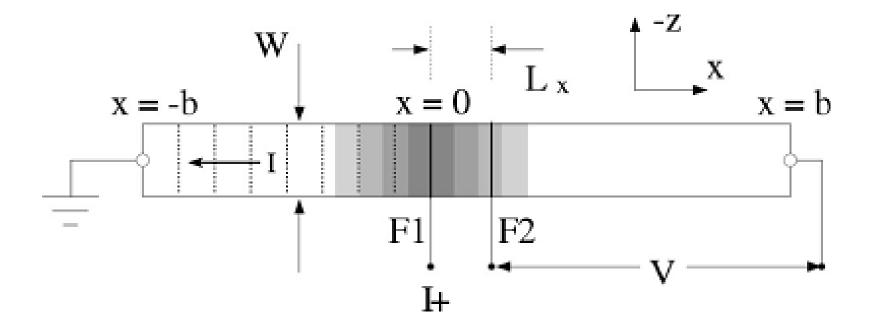
$$L_{SF} = \sqrt{D_{SF}\tau_{sF}}$$

$$L_{SN} = \sqrt{D_{SN}\tau_{SN}}$$

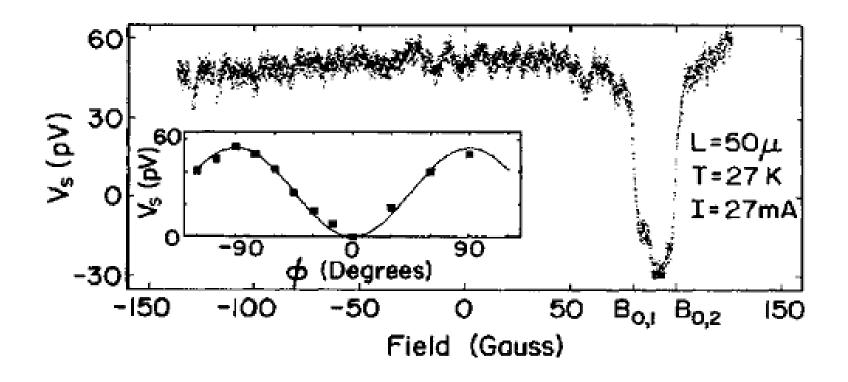
Diffusion equation:

$$abla^2 \mu_{SF} = \mu_{SF}/LSF^2$$

$$abla^2 \mu_{SN} = \mu_{SN}/LSN^2$$



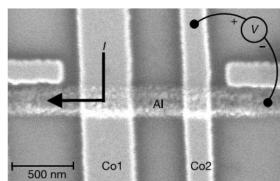
Johnson & Silsbee, PRL (1985)

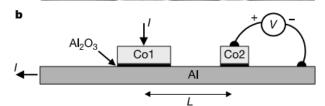


Johnson & Silsbee, PRL (1985)

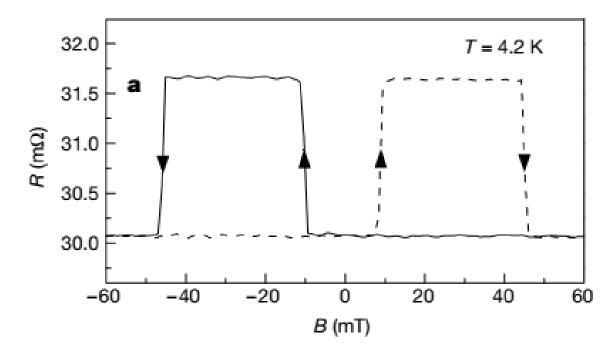
Electron beam lithography





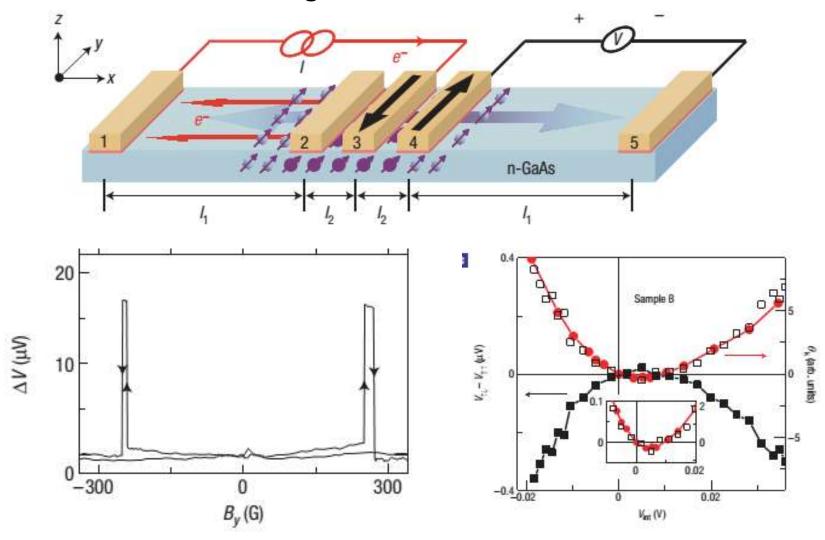


Nano Devices: spin diffusion length ~ μm

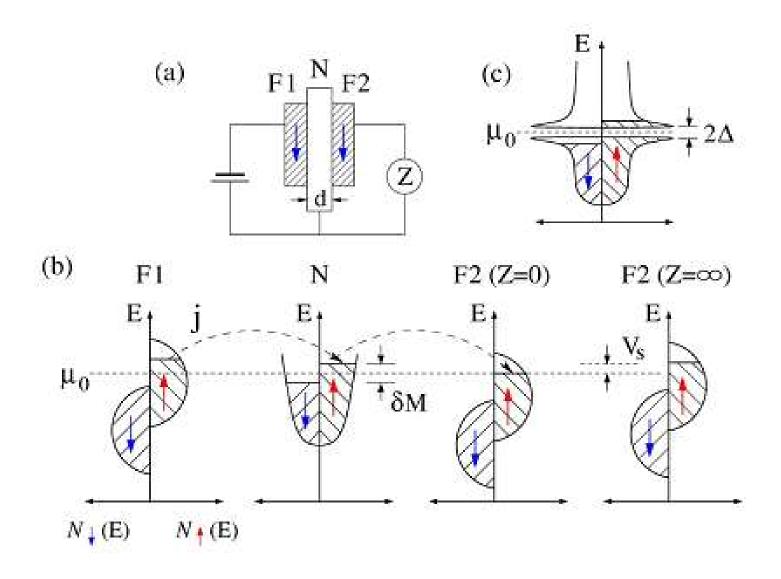


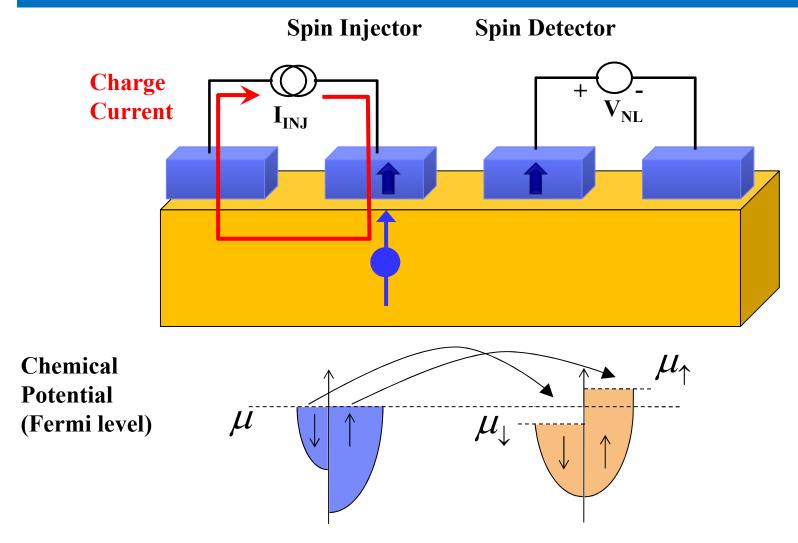
Jedema, et al, Nature (2001) Jedema, et al, Nature (2002)

GaAs: a semiconducting channel



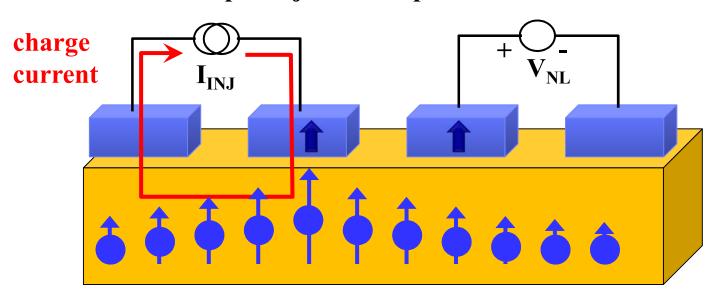
Electrical Spin detection



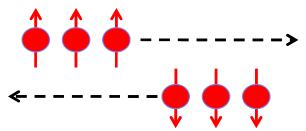


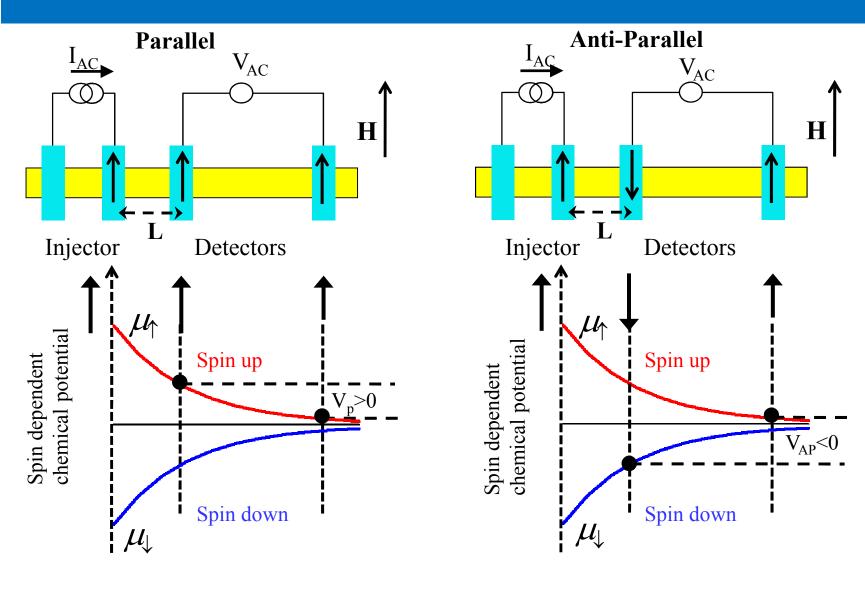
Johnson and Silsbee, PRL (1985)

Spin Injector Spin Detector

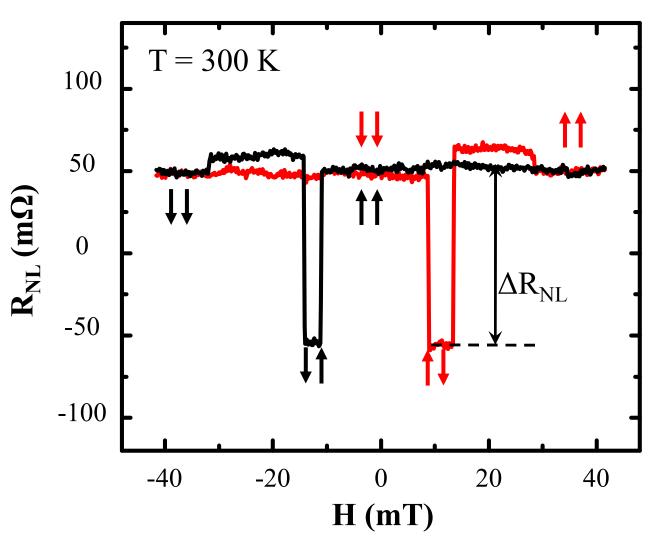


Pure spin current: Flow of spin without net flow of charge





Nonlocal MR = $(V_P - V_{AP})/I_{INJ}$



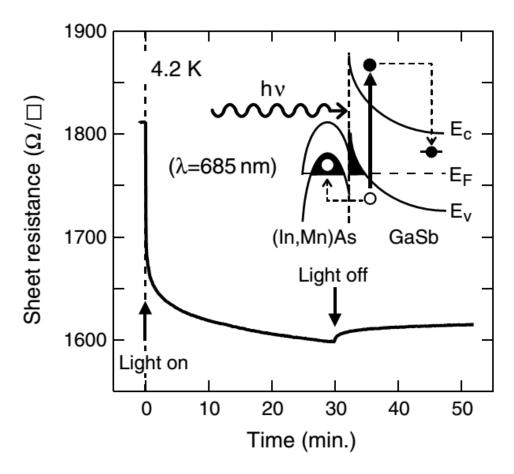
Han, et al, APL (2009) $_{72}$

Electrical Spin injection

3. Spin injection

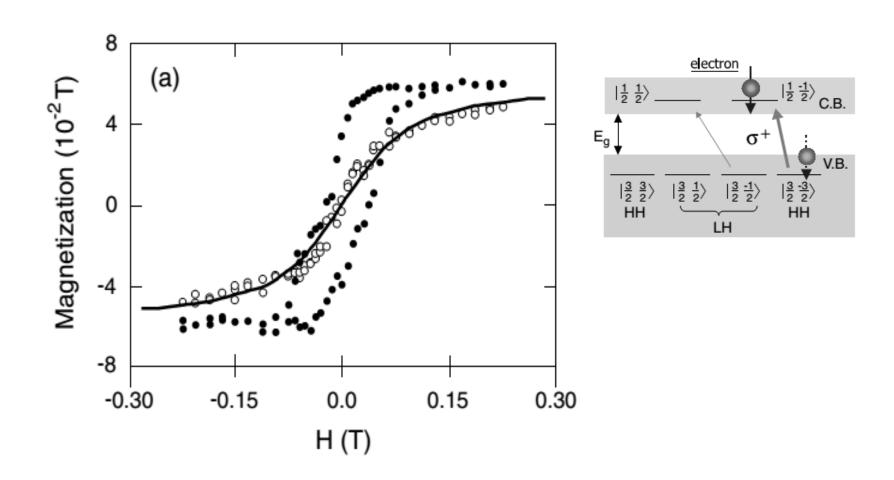
□ Optical

GaMnAs

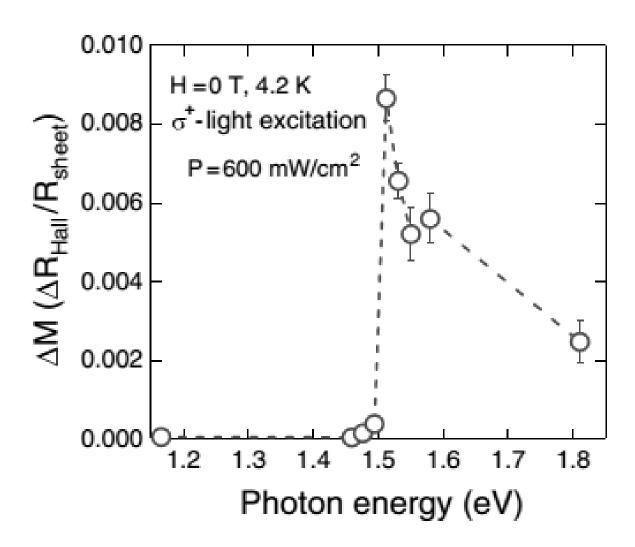


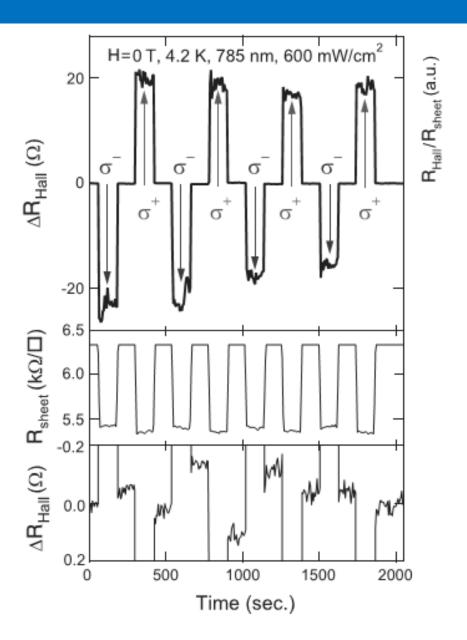
Maekawa, Book Concepts in Spin electronics (2006)

GaMnAs



GaMnAs





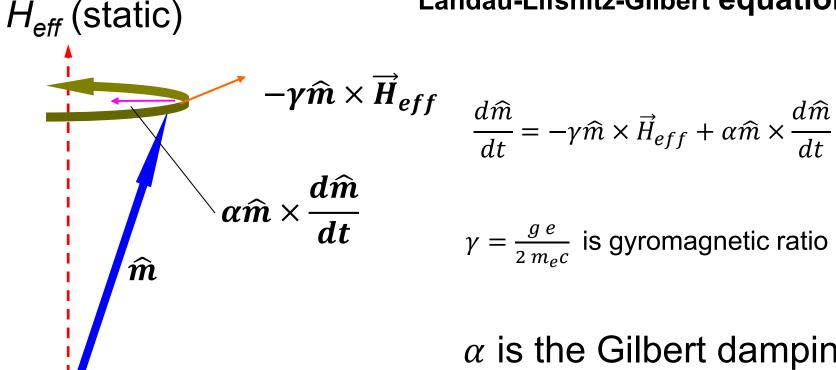
Electrical Spin injection

3. Spin injection

☐ Dynamical

Magnetic resonance



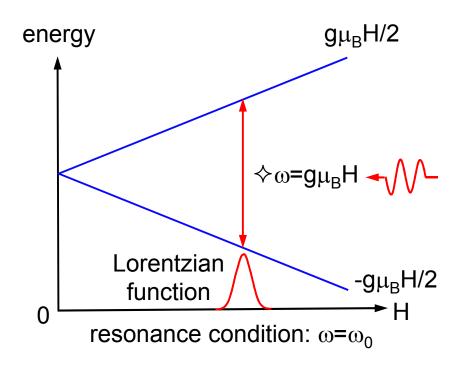


 α is the Gilbert damping

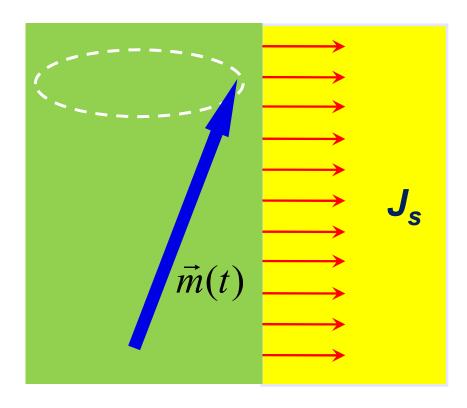
 $H_x e^{i\omega t}$ (rf): small perturbation

Magnetic resonance

FMR



FM NM



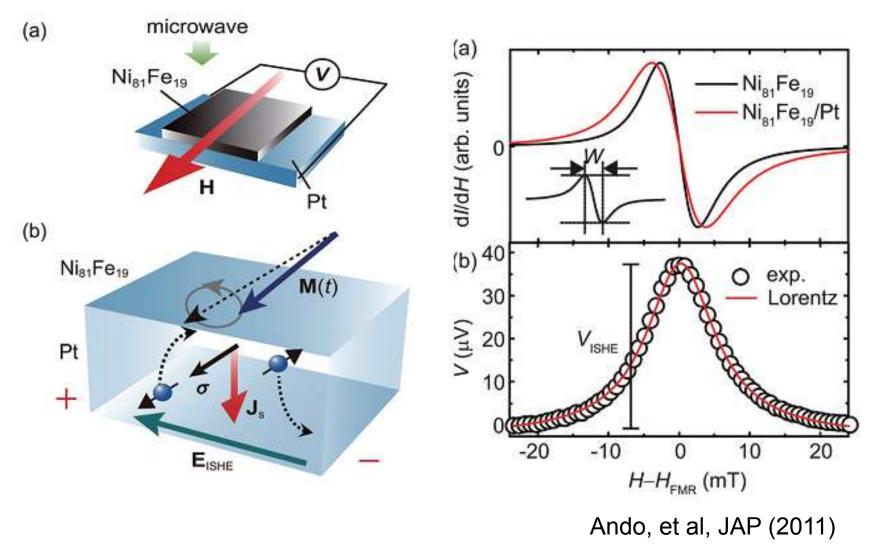
$$\vec{J}_S = \frac{\hbar g_r^{\uparrow\downarrow}}{4\pi M^2} \left(\vec{M} \times \frac{\partial \vec{M}}{\partial t} \right)$$

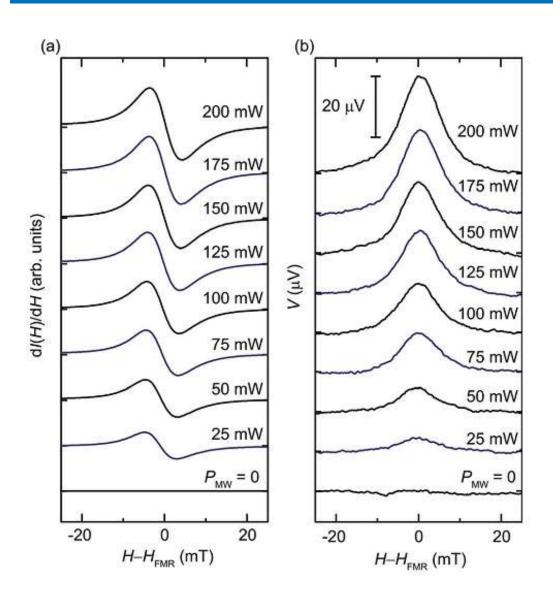
Precessing magnetization in FM layer pump spin current into NM layer (Angular momentum conservatoin)

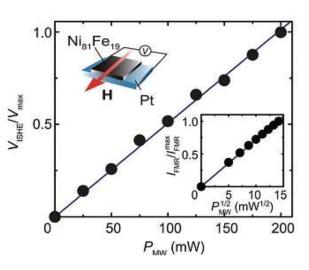
$$\frac{d\mathbf{M}(t)}{dt} = -\gamma \mathbf{M}(t) \times \mathbf{H}_{\text{eff}} + \frac{\alpha}{M_s} \mathbf{M}(t) \times \frac{d\mathbf{M}(t)}{dt}.$$

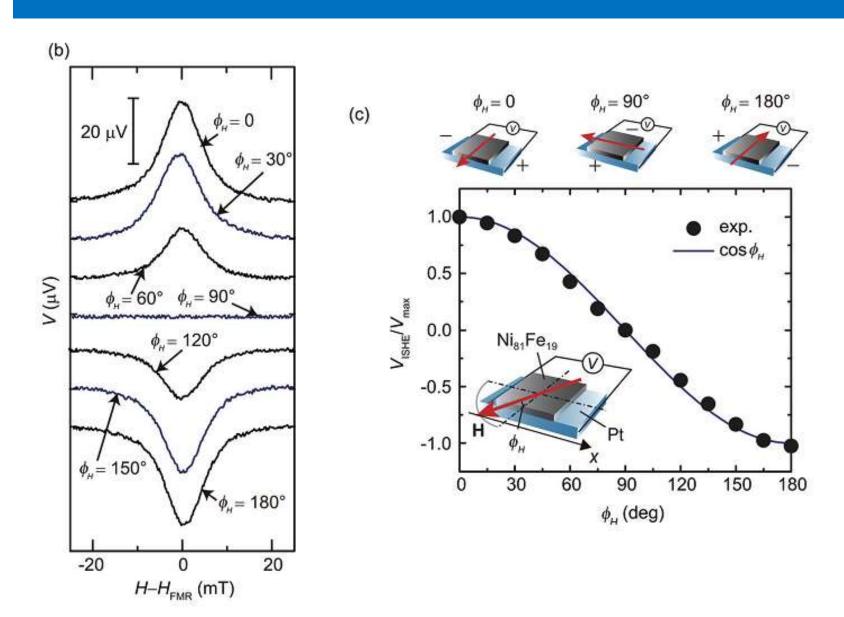
$$\tau = -\mathbf{m} \times \mathbf{I}_s \times \mathbf{m}$$
.

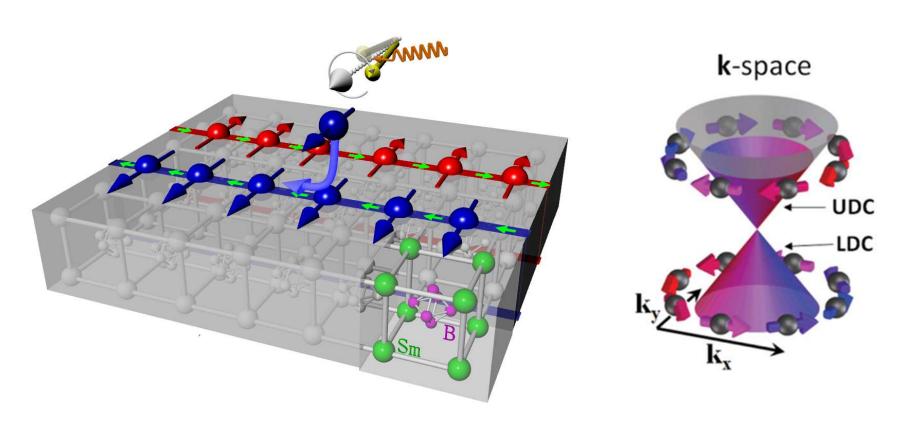
$$\mathbf{I}_{s,R}^{\text{pump}} = \frac{\hbar}{4\pi} \left(\mathcal{A}_r^{\uparrow\downarrow} \mathbf{m} \times \frac{d\mathbf{m}}{dt} + \mathcal{A}_i^{\uparrow\downarrow} \frac{d\mathbf{m}}{dt} \right)$$



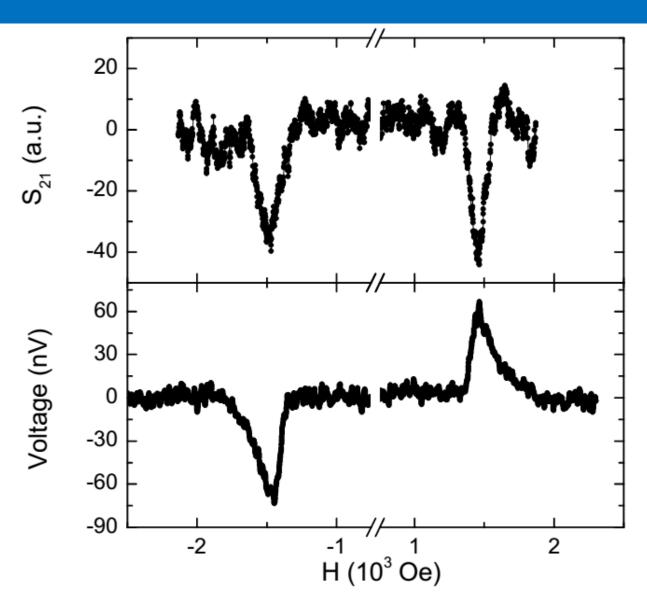


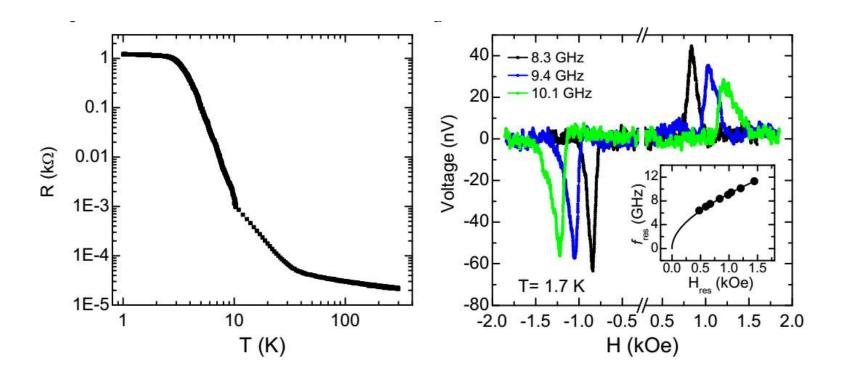




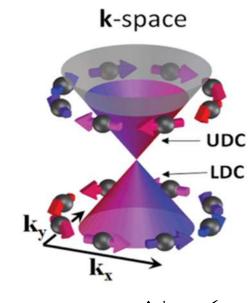


Spin-Momentum Locking

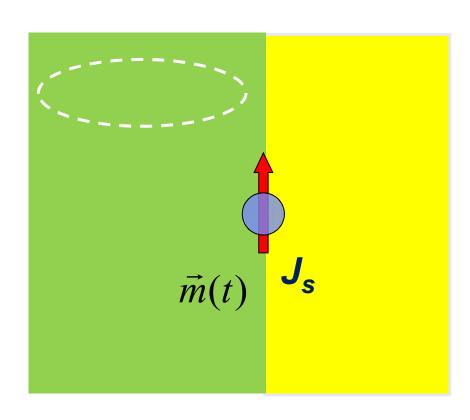




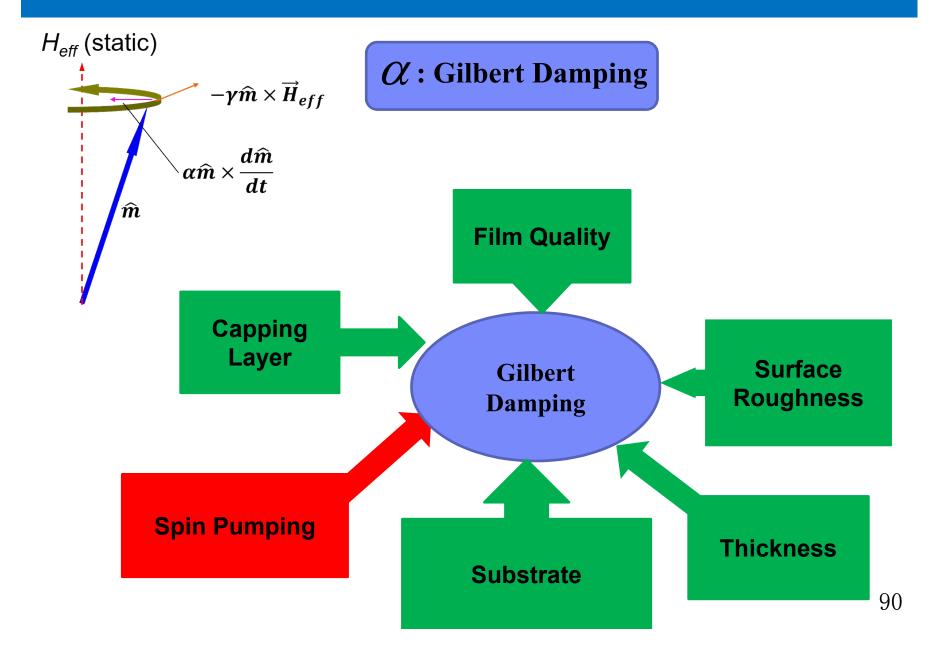
Song, et al, Nature Communications (2016)

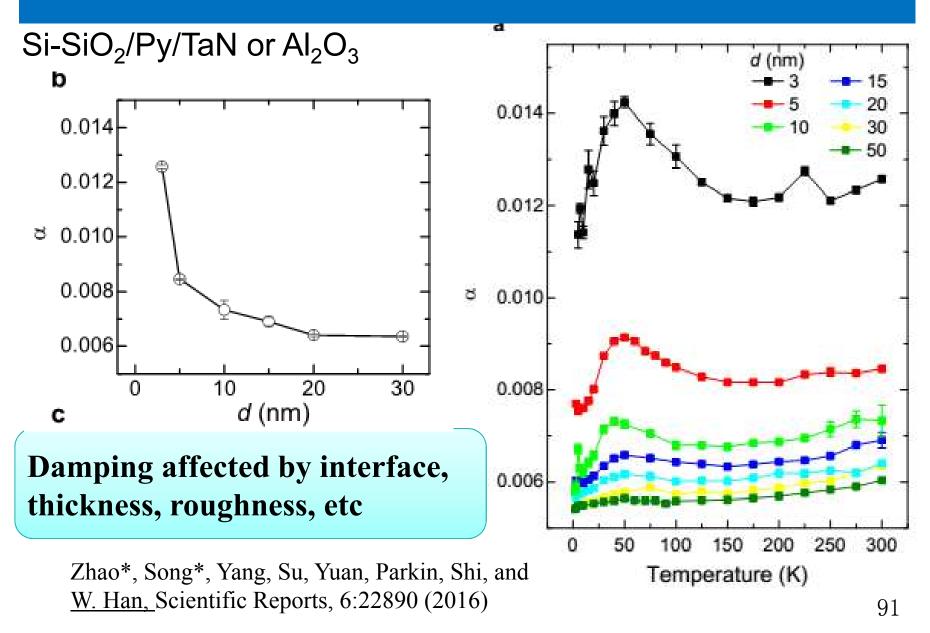


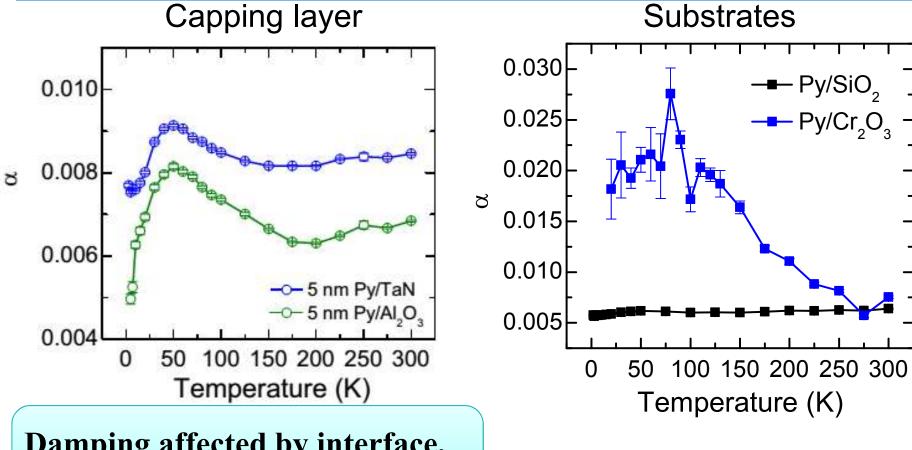
$$\vec{J}_S = \frac{\hbar g_r^{\uparrow\downarrow}}{4\pi M^2} \left(\vec{M} \times \frac{\partial \vec{M}}{\partial t} \right)$$



Enhanced Gilbert Damping



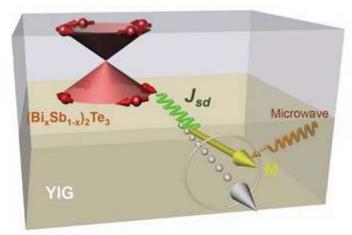




Damping affected by interface, thickness, roughness, etc

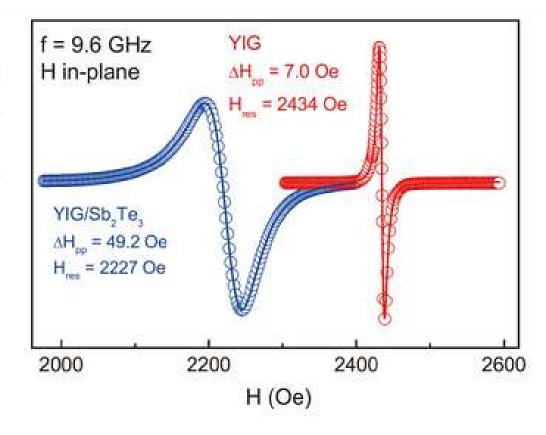
Zhao*, Song*, Yang, Su, Yuan, Parkin, Shi, and W. Han, Scientific Reports, 6:22890 (2016)

Song, et al, unpublished



 $H_{sd} = J_{sd} \sum_{i \in FM/NM \ interface} \vec{\sigma}_i \cdot \vec{s}_i$

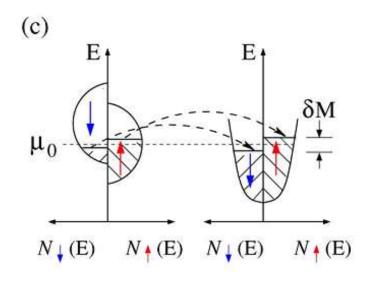
Enhanced Gilbert damping FMR absorption



Summary

3. Spin injection

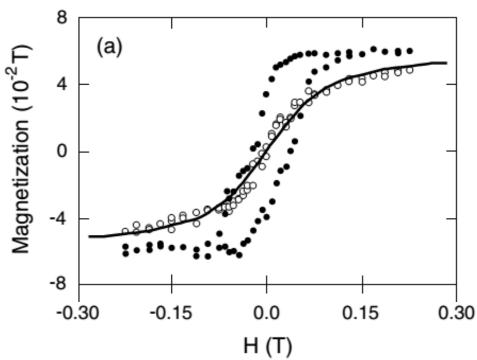
☐ Electrical



Summary

3. Spin injection

☐ Optical

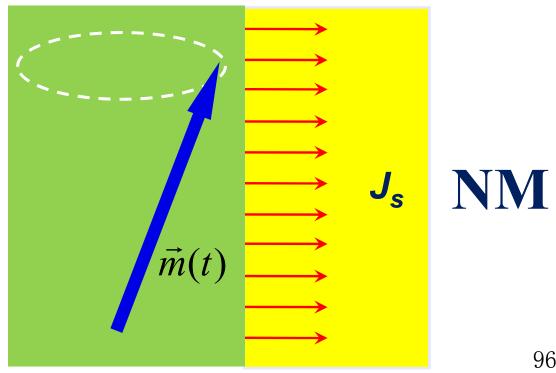


Summary

3. Spin injection

□ Dynamical

FM



下一节课: Oct. 27th

Homework 2 due!

下一节课: Oct. 27th

Chapter 4: Spin Valves

2. Spin valves based on Metal and Superconductor

课件下载:

http://www.phy.pku.edu.cn/~LabSpin/teaching.html

谢谢!